# Silicon Carbide (SiC) Cascode JFET – EliteSiC, Power N-Channel, TO-263-7, 1200 V, 85 mohm

# **UF3C120080B7S**

# Description

This SiC FET device is based on a unique 'cascode' circuit configuration, in which a normally-on SiC JFET is co-packaged with a Si MOSFET to produce a normally-off SiC FET device. The device's standard gate-drive characteristics allows for a true "drop-in replacement" to Si IGBTs, Si FETs, SiC MOSFETs or Si superjunction devices. Available in the TO-263-7 package, this device exhibits ultra-low gate charge and exceptional reverse recovery characteristics, making it ideal for switching inductive loads, and any application requiring standard gate drive.

#### **Features**

- On-resistance  $R_{DS(on)}$ : 85 m $\Omega$  (Typ)
- Operating Temperature: 175 °C (Max)
- Excellent Reverse Recovery:  $Q_{rr} = 140 \text{ nC}$
- Low Body Diode V<sub>FSD</sub>: 1.5 V
- Low Gate Charge:  $Q_G = 23 \text{ nC}$
- Threshold Voltage V<sub>G(th)</sub>: 4.8 V (Typ) Allowing 0 to 15 V Drive
- Package Creepage and Clearance Distance > 6.1 mm
- Kelvin Source Pin for Optimized Switching Performance
- ESD Protected, HBM Class 2
- This Device is Pb-Free, Halogen Free and is RoHS Compliant

1

# **Typical Applications**

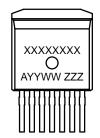
Any controlled environment such as

- Telecom and Server Power
- Industrial Power Supplies
- Power Factor Correction Modules
- Motor Drives
- Induction Heating



TO-263-7 10.18x9.08x4.43, 1.27P CASE 418BA

#### MARKING DIAGRAM

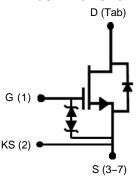


XXXXXXX = Specific Device Code

A = Assembly Location
YY = Year
WW = Work Week

ZZZ = Lot ID

#### **PIN CONNECTIONS**



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 8 of this data sheet.

# **MAXIMUM RATINGS**

Parameter	Symbol	Test Conditions	Value	Unit
Drain-source Voltage	V <sub>DS</sub>		1200	V
Gate-source Voltage	$V_{GS}$	DC	−25 to +25	V
Continuous Drain Current (Note 1)	I <sub>D</sub>	T <sub>C</sub> = 25 °C	28.8	Α
		T <sub>C</sub> = 100 °C	21	Α
Pulsed Drain Current (Note 2)	I <sub>DM</sub>	T <sub>C</sub> = 25 °C	77	Α
Single Pulsed Avalanche Energy (Note 3)	E <sub>AS</sub>	L = 15 mH, I <sub>AS</sub> = 2.8 A	58.5	mJ
Power Dissipation	P <sub>tot</sub>	T <sub>C</sub> = 25 °C	190	W
Maximum Junction Temperature	$T_{J,max}$		175	°C
Operating and Storage Temperature	T <sub>J</sub> , T <sub>STG</sub>		-55 to 175	°C
Reflow Soldering Temperature	T <sub>solder</sub>	Reflow MSL 3	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Limited by T<sub>J,max</sub>
2. Pulse width t<sub>p</sub> limited by T<sub>J,max</sub>
3. Starting T<sub>J</sub> = 25 °C

#### THERMAL CHARACTERISTICS

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$		-	0.61	0.79	°C/W

# **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = +25 $^{\circ}$ C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
TYPICAL PERFORMANCE – STATIC	•			•		
Drain-source Breakdown Voltage	BV <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = 1 \text{ mA}$	1200	_	_	V
Total Drain Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> = 1200 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 25 °C	-	0.7	75	μΑ
		$V_{DS} = 1200 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$	-	3	_	
Total Gate Leakage Current	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V, } T_{J} = 25 \text{ °C,}$ $V_{GS} = -20 \text{ V / } +20 \text{ V}$	-	6	±20	μΑ
Drain-source On-resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 12 V, I <sub>D</sub> = 20 A, T <sub>J</sub> = 25 °C	-	85	105	mΩ
		V <sub>GS</sub> = 12 V, I <sub>D</sub> = 20 A, T <sub>J</sub> = 125 °C	-	135	_	
		V <sub>GS</sub> = 12 V, I <sub>D</sub> = 20 A, T <sub>J</sub> = 175 °C	-	177	_	
Gate Threshold Voltage	V <sub>G(th)</sub>	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 10 mA	4	4.8	6	V
Gate Resistance	$R_{G}$	f = 1 MHz, open drain	-	4.2	_	Ω
TYPICAL PERFORMANCE – REVERSE DIO	DE					
Diode Continuous Forward Current (Note 4)	IS	T <sub>C</sub> = 25 °C	-	_	28.8	Α
Diode Pulse Current (Note 5)	I <sub>S,pulse</sub>	T <sub>C</sub> = 25 °C	-	-	77	Α
Forward Voltage	V <sub>FSD</sub>	$V_{GS} = 0 \text{ V}, I_S = 10 \text{ A}, T_J = 25 ^{\circ}\text{C}$	-	1.5	2	V
		V <sub>GS</sub> = 0 V, I <sub>S</sub> = 10 A, T <sub>J</sub> = 175 °C	-	2	_	
Reverse Recovery Charge	$Q_{rr}$	$V_{DS} = 800 \text{ V}, I_{S} = 20 \text{ A}, V_{GS} = -5 \text{ V},$	-	140	_	nC
Reverse Recovery Time	t <sub>rr</sub>	$R_{G\_EXT}$ = 22 $\Omega$ , di/dt = 2800 A/ $\mu$ s, $T_{J}$ = 25 °C	_	23	_	ns
Reverse Recovery Charge	Q <sub>rr</sub>	$V_{DS} = 800 \text{ V}, I_{S} = 20 \text{ A}, V_{GS} = -5 \text{ V},$	_	118	-	nC
Reverse Recovery Time	t <sub>rr</sub>	$R_{G\_EXT} = 22 \Omega$ , di/dt = 2800 A/µs, $T_{J} = 150 ^{\circ}\text{C}$	_	19	_	ns

**ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = +25  $^{\circ}$ C unless otherwise specified) (continued)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
TYPICAL PERFORMANCE – DYNAMIC						•
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V, f = 100 kHz	-	754	_	pF
Output Capacitance	C <sub>oss</sub>	1 = 100 KHZ	-	97	-	]
Reverse Transfer Capacitance	C <sub>rss</sub>		-	0.8	-	]
Effective Output Capacitance, Energy Related	C <sub>oss(er)</sub>	V <sub>DS</sub> = 0 V to 800 V, V <sub>GS</sub> = 0 V	-	54	-	pF
Effective Output Capacitance, Time Related	C <sub>oss(tr)</sub>	V <sub>DS</sub> = 0 V to 800 V, V <sub>GS</sub> = 0 V	-	122	-	pF
C <sub>OSS</sub> Stored Energy	E <sub>oss</sub>	V <sub>DS</sub> = 800 V, V <sub>GS</sub> = 0 V	-	17.3	-	μJ
Total gate Charge	$Q_{G}$	$V_{DS} = 800 \text{ V}, I_{D} = 20 \text{ A},$	-	23	-	nC
Gate-drain Charge	$Q_{GD}$	$V_{GS} = -5 \text{ V to } 12 \text{ V}$	-	5	-	]
Gate-source Charge	Q <sub>GS</sub>		-	11	-	]
Turn-on Delay Time	t <sub>d(on)</sub>	$V_{DS} = 800 \text{ V, } I_{D} = 20 \text{ A,}$ $Gate \ Driver = -5 \text{ V to } +12 \text{ V,}$ $Turn\text{-on } R_{G,EXT} = 8.5 \Omega,$ $Turn\text{-off } R_{G,EXT} = 22 \Omega$ $Inductive \ Load,$ $FWD: \text{ same device with } V_{GS} = -5 \text{ V,}$ $R_{G} = 22 \Omega, T_{J} = 25 \text{ °C}$	-	33	-	ns
Rise Time	t <sub>r</sub>		-	7	_	]
Turn-off Delay Time	t <sub>d(off)</sub>		-	30	_	]
Fall Time	t <sub>f</sub>		-	9	_	]
Turn-on Energy	E <sub>ON</sub>	11.6 – 22 32, 11 – 23 0	-	340	_	μJ
Turn-off Energy	E <sub>OFF</sub>		-	48	_	]
Total Switching Energy	E <sub>TOTAL</sub>		-	388	-	
Turn-on Delay Time	t <sub>d(on)</sub>	$V_{DS} = 800 \text{ V}, I_{D} = 20 \text{ A},$	-	31	-	ns
Rise Time	t <sub>r</sub>	Gate Driver = $-5$ V to +12 V, Turn-on R <sub>G,EXT</sub> = 8.5 $\Omega$ ,	-	6	-	
Turn-off Delay Time	t <sub>d(off)</sub>	Turn-off $R_{G,EXT}$ = 22 $\Omega$ Inductive Load, FWD: same device with $V_{GS}$ = -5 V,	1	30	_	1
Fall Time	t <sub>f</sub>		-	8	-	
Turn-on Energy	E <sub>ON</sub>	$R_G = 22 Ω, T_J = 150 °C$	-	312	-	μJ
Turn-off Energy	E <sub>OFF</sub>		-	42	-	
Total Switching Energy	E <sub>TOTAL</sub>		1	354	_	]

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Limited by T<sub>J,max</sub>

5. Pulse width t<sub>p</sub> limited by T<sub>J,max</sub>

#### **TYPICAL PERFORMANCE DIAGRAMS**

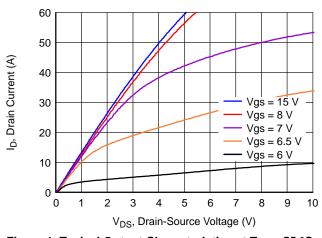


Figure 1. Typical Output Characteristics at T  $_J$  = -55 °C,  $t_p$  < 250  $\mu s$ 

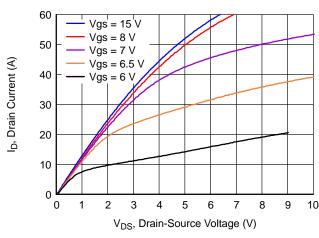


Figure 2. Typical Output Characteristics at  $T_J$  = 25 °C,  $t_n$  < 250  $\mu s$ 

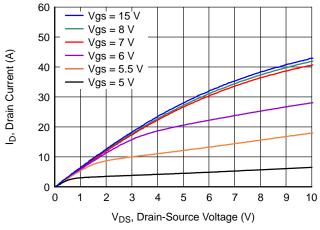


Figure 3. Typical Output Characteristics at T  $_{J}$  = 175 °C,  $t_{p}$  < 250  $\mu s$ 

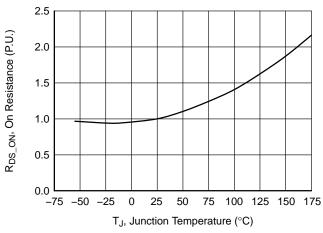


Figure 4. Normalized On-Resistance vs. Temperature at  $V_{GS}$  = 12 V and  $I_D$  = 20 A

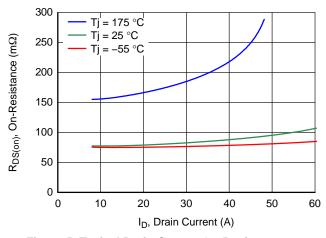


Figure 5. Typical Drain-Source On-Resistances at  $V_{GS} = 12 \text{ V}$ 

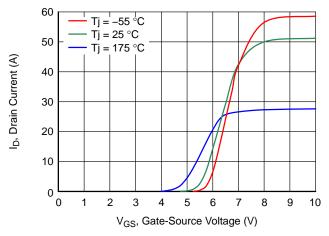


Figure 6. Typical Transfer Characteristics at V<sub>DS</sub> = 5 V

# TYPICAL PERFORMANCE DIAGRAMS (CONTINUED)

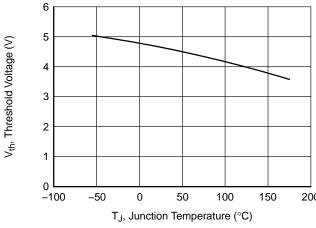


Figure 7. Threshold Voltage vs. Junction Temperature at  $V_{DS}$  = 5 V and  $I_{D}$  = 10 mA

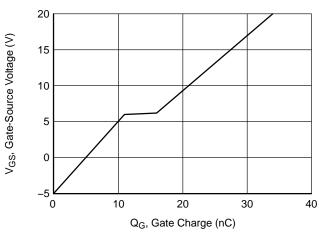


Figure 8. Typical Gate Charge at  $V_{DS}$  = 800 V and  $I_{D}$  = 20 A

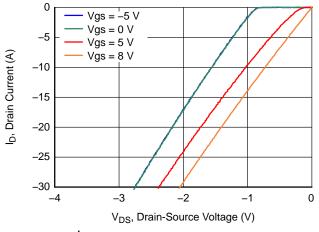


Figure 9.  $3^{rd}$  Quadrant Characteristics at  $T_J = -55$  °C

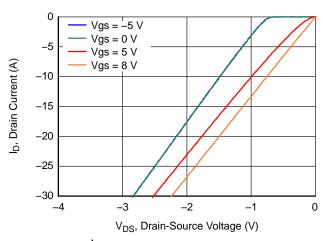


Figure 10. 3<sup>rd</sup> Quadrant Characteristics at T<sub>J</sub> = 25 °C

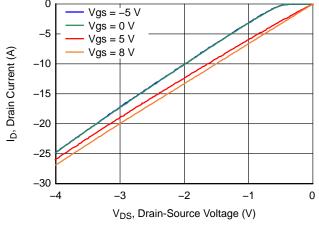


Figure 11. 3<sup>rd</sup> Quadrant Characteristics at T<sub>J</sub> = 175 °C

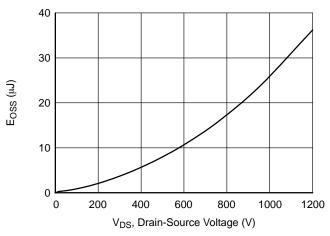


Figure 12. Typical Stored Energy in C<sub>OSS</sub> at V<sub>GS</sub> = 0 V

# TYPICAL PERFORMANCE DIAGRAMS (CONTINUED)

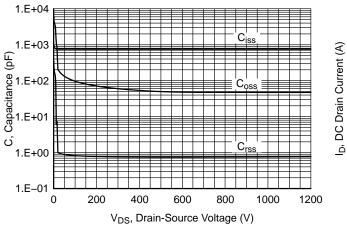


Figure 13. Typical Capacitances at f = 100 kHz and  $V_{GS}$  = 0 V

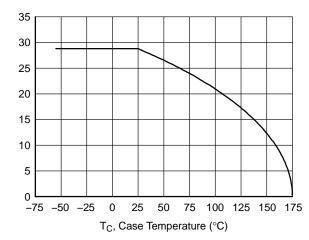
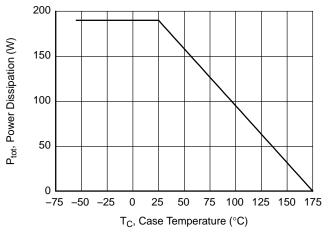


Figure 14. DC Drain Current Derating



**Figure 15. Total Power Dissipation** 

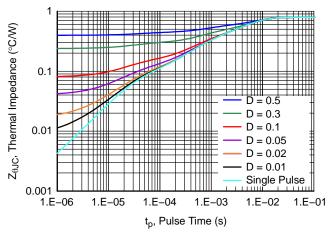


Figure 16. Maximum Transient Thermal Impedance

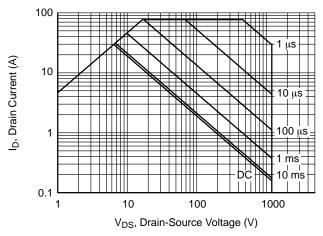


Figure 17. Safe Operation Area at  $T_C$  = 25 °C, D = 0, Parameter  $t_p$ 

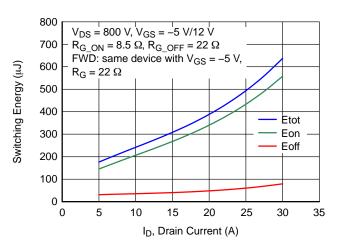


Figure 18. Clamped Inductive Switching Energy vs. Drain Current at  $T_J = 25$  °C

# TYPICAL PERFORMANCE DIAGRAMS (CONTINUED)

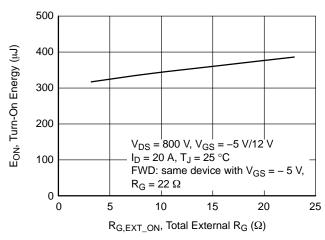


Figure 19. Clamped Inductive Switching Turn-on Energy vs. R<sub>G,EXT\_ON</sub>

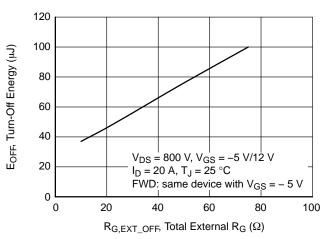


Figure 20. Clamped Inductive Switching Turn-off Energy vs. R<sub>G,EXT OFF</sub>

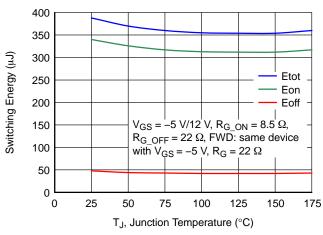


Figure 21. Clamped Inductive Switching Energy vs. Junction Temperature at  $V_{DS}$  = 800 V and  $I_{D}$  = 20 A

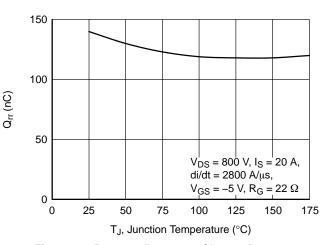


Figure 22. Reverse Recovery Charge Q<sub>rr</sub> vs. Junction Temperature

#### APPLICATIONS INFORMATION

SiC FETs are enhancement-mode power switches formed by a high-voltage SiC depletion-mode JFET and a low-voltage silicon MOSFET connected in series. The silicon MOSFET serves as the control unit while the SiC JFET provides high voltage blocking in the off state. This combination of devices in a single package provides compatibility with standard gate drivers and offers superior performance in terms of low on-resistance ( $R_{DS(on)}$ ), output capacitance ( $C_{oss}$ ), gate charge ( $Q_G$ ), and reverse recovery charge ( $Q_{rr}$ ) leading to low conduction and switching losses. The SiC FETs also provide excellent reverse conduction capability eliminating the need for an external anti-parallel diode.

Like other high performance power switches, proper PCB layout design to minimize circuit parasitics is strongly recommended due to the high dv/dt and di/dt rates. An external gate resistor is recommended when the FET is

working in the diode mode in order to achieve the optimum reverse recovery performance. For more information on SiC FET operation, see <a href="https://www.onsemi.com">www.onsemi.com</a>.

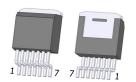
A snubber circuit with a small  $R_{(G)}$ , or gate resistor, provides better EMI suppression with higher efficiency compared to using a high  $R_{(G)}$  value. There is no extra gate delay time when using the snubber circuitry, and a small  $R_{(G)}$  will better control both the turn-off  $V_{(DS)}$  peak spike and ringing duration, while a high  $R_{(G)}$  will damp the peak spike but result in a longer delay time. In addition, the total switching loss when using a snubber circuit is less than using high  $R_{(G)}$ , while greatly reducing  $E_{(OFF)}$  from mid-to-full load range with only a small increase in  $E_{(ON)}$ . Efficiency will therefore improve with higher load current. For more information on how a snubber circuit will improve overall system performance, visit the **onsemi** website at www.onsemi.com.

#### **ORDERING INFORMATION**

Part Number	Marking	Package	Shipping <sup>†</sup>
UF3C120080B7S	UF3C120080B7S	TO-263-7 10.18x9.08x4.43, 1.27P (Pb-Free, Halogen Free)	800 / Tape and Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



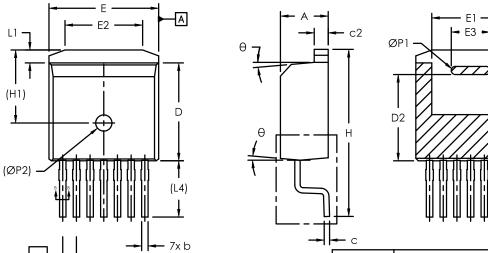


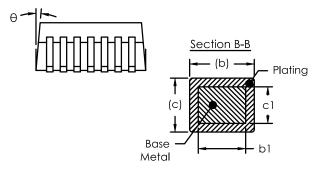
#### TO-263-7 10.18x9.08x4.43, 1.27P CASE 418BA ISSUE B

**DATE 17 APR 2025** 

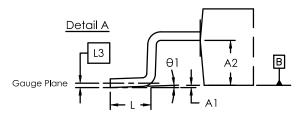
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(H3)





**⊕** 0.25mm **M** B A **M** 



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- 1. Dimensioning and Tolerancing as per ASME Y14.5M, 2018.
- 2. Controlling Dimension: Millimeters
- 3. Package body sides exclude mold flash and gate burrs.
- 4. Dimension L is measured on gauge plane.
- 5. Dimension c1 and b1 applies to base metal only.

Min         Nom         Max           A         4.30         4.43         4.56           A1         0.00         0.13         0.25           A2         2.45         2.60         2.75           b         0.50         0.60         0.70           b1         0.50         -         -           c         0.40         -         -           c2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF           L         1.90         2.20         2.50           L1         0.98         1.20         1.42     <	SYM		MILLIMETERS			
A1       0.00       0.13       0.25         A2       2.45       2.60       2.75         b       0.50       0.60       0.70         b1       0.50       -       -         c       0.40       0.50       0.60         c1       0.40       -       -         c2       1.20       1.30       1.40         D       8.93       9.08       9.23         D1       5.85       6.00       6.15         D2       7.90       8.00       8.10         e       1.27 BSC         E       10.08       10.18       10.28         E1       6.82       7.22       7.62         E2       6.50       7.55       8.60         E3       3.50       3.60       3.70         H       15.00       15.50       16.00         H1       6.78 REF         H3       7.30 REF         L       1.90       2.20       2.50         L1       0.98       1.20       1.42         L3       0.25 BSC       1.44       5.22 REF         ØP1       0.65       0.75       0.85	311/1	Min	Nom	Мах		
A2       2.45       2.60       2.75         b       0.50       0.60       0.70         b1       0.50       -       -         c       0.40       0.50       0.60         c1       0.40       -       -         c2       1.20       1.30       1.40         D       8.93       9.08       9.23         D1       5.85       6.00       6.15         D2       7.90       8.00       8.10         e       1.27 BSC         E       10.08       10.18       10.28         E1       6.82       7.22       7.62         E2       6.50       7.55       8.60         E3       3.50       3.60       3.70         H       15.00       15.50       16.00         H1       6.78 REF         H3       7.30 REF         L       1.90       2.20       2.50         L1       0.98       1.20       1.42         L3       0.25 BSC       1.4       5.22 REF         ØP1       0.65       0.75       0.85         ØP2       1.50 REF       5°	Α	4.30	4.43	4.56		
b         0.50         0.60         0.70           b1         0.50         -         -           c         0.40         0.50         0.60           c1         0.40         -         -           c2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF	A1	0.00	0.13	0.25		
b1         0.50         -         -           c         0.40         0.50         0.60           c1         0.40         -         -           c2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF         5°	A2	2.45	2.60	2.75		
C         0.40         0.50         0.60           c1         0.40         -         -           c2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC         E           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF         5°	b	0.50	0.60	0.70		
C1         0.40         -         -           C2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF         5°	b1	0.50	-	=		
C2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           6         5°	С	0.40	0.50	0.60		
D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           Θ         5°	c1	0.40	-	-		
D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           6         5°	c2	1.20	1.30	1.40		
D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           Θ         5°	D	8.93	9.08	9.23		
e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           Θ         5°	D1	5.85	6.00	6.15		
E 10.08 10.18 10.28 E1 6.82 7.22 7.62 E2 6.50 7.55 8.60 E3 3.50 3.60 3.70 H 15.00 15.50 16.00 H1 6.78 REF H3 7.30 REF. L 1.90 2.20 2.50 L1 0.98 1.20 1.42 L3 0.25 BSC L4 5.22 REF ØP1 0.65 0.75 0.85 ØP2 1.50 REF	D2	7.90	8.00	8.10		
E1 6.82 7.22 7.62 E2 6.50 7.55 8.60 E3 3.50 3.60 3.70 H 15.00 15.50 16.00 H1 6.78 REF H3 7.30 REF. L 1.90 2.20 2.50 L1 0.98 1.20 1.42 L3 0.25 BSC L4 5.22 REF ØP1 0.65 0.75 0.85 ØP2 1.50 REF		1.27 BSC				
E2       6.50       7.55       8.60         E3       3.50       3.60       3.70         H       15.00       15.50       16.00         H1       6.78 REF         H3       7.30 REF.         L       1.90       2.20       2.50         L1       0.98       1.20       1.42         L3       0.25 BSC         L4       5.22 REF         ØP1       0.65       0.75       0.85         ØP2       1.50 REF         Θ       5°	Е	10.08	10.18	10.28		
E3 3.50 3.60 3.70  H 15.00 15.50 16.00  H1 6.78 REF  H3 7.30 REF.  L 1.90 2.20 2.50  L1 0.98 1.20 1.42  L3 0.25 BSC  L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  Θ 5°	E1	6.82	7.22	7.62		
H 15.00 15.50 16.00  H1 6.78 REF  H3 7.30 REF.  L 1.90 2.20 2.50  L1 0.98 1.20 1.42  L3 0.25 BSC  L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  Θ 5°	E2	6.50	7.55	8.60		
H1 6.78 REF H3 7.30 REF.  L 1.90 2.20 2.50  L1 0.98 1.20 1.42  L3 0.25 BSC  L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  Θ 5°	E3	3.50	3.60	3.70		
H3 7.30 REF.  L 1.90 2.20 2.50  L1 0.98 1.20 1.42  L3 0.25 BSC  L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  Θ 5°	Н	15.00	15.50	16.00		
L 1.90 2.20 2.50 L1 0.98 1.20 1.42 L3 0.25 BSC L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  θ 5°	H1		6.78 REF			
L1     0.98     1.20     1.42       L3     0.25 BSC       L4     5.22 REF       ØP1     0.65     0.75     0.85       ØP2     1.50 REF       Θ     5°	Н3		7.30 REF.			
L3     0.25 BSC       L4     5.22 REF       ØP1     0.65     0.75     0.85       ØP2     1.50 REF       Θ     5°		1.90	2.20	2.50		
L4     5.22 REF       ØP1     0.65     0.75     0.85       ØP2     1.50 REF       Θ     5°	L1	0.98	1.20	1.42		
ØP1         0.65         0.75         0.85           ØP2         1.50 REF           θ         5°	L3					
ØP2 1.50 REF Θ 5°	L4	5.22 REF				
θ 5°	ØP1	0.65	0.75	0.85		
	ØP2					
01 20	θ					
	θ1	3°				

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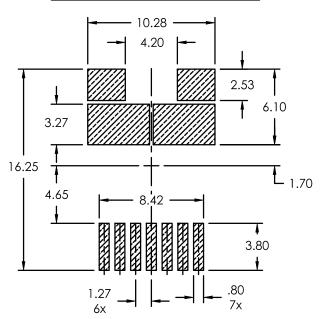
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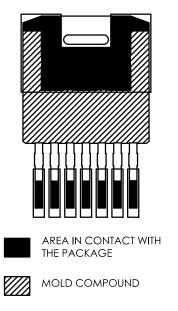
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